IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant	Michael Heuken		
Serial No Pending Filing Date: November 17, 2003			
Title of Application:	Method And Device For Depositing Layers		
Confirmation No.	Art Unit:		
Examiner			

Commissioner for Patents Post Office Box 1450 Alexandria, VA 22313-1450

Information Disclosure Statement by Applicant

Dear Sir:

As a means of complying with the duty of disclosure set forth in 37 CFR §1.56, Applicant lists the following references (copies of the listed patents and papers enclosed).

U.S. Patent Documents						
Exam. Initials	Class/ Subclass.	Document No.	Date	Name		
5,1	118/733	4,976,217	12/1990	Frijlink		
4	118/715	4,991,540	2/1991	Jürgensen et al.		
	437/110	5,162,256	11/1992	Jürgensen		
	117/91	5,348,911	9/1994	Jürgensen et al.		
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	118/715	5,453,124	9/1995	Moslehi et al.		
	118/725	5,595,606	1/1997	Fujikawa et al.		
7	134/22.14	5,709,757	1/1998	Hatano et al.		
1	117/103	5,772,759	6/1998	Heime et al.		
1	118/715	6,086,677	7/2000	Umotoy et al.		
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Foreign Patent Documents					
Exam. Initials	Document No.	Date	Country		
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	WO 87/05700	9/1987	PCT		
	36 08 783 C2	9/1987	DE (with English abstract)		
	0 233 610 B1	8/1987	EP		
	0 243 416 B1	4/1987	EP		
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	0 428 673 B1	5/1991	EP (with English abstract)		
	WO 91/20093	12/1991	PCT		
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	195 40 771 A1	7/1997	DE (with English abstract)		
	198 13 523 A1	10/1999	DE (with English abstract)		
In 1	WO 99/15710	4/1999	PCT		

	Other Documents					
Exam. Initials	Description (Author, Title, Date, Pages, etc)					
4	Characterization of Epitaxal Semiconductor Growth, J.T. Zettler, Progression of Crystal Growth and Characterization, Vol 35, pp. 27-98, 1997					

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